

## TPS2290x 具有受控开通功能的 3.6V、500mA、78mΩ 导通电阻负载开关

### 1 特性

- 集成 P 沟道负载开关
- 低输入电压：1V 至 3.6V
- 导通电阻 (典型值)
  - $V_{IN} = 3.6V$  时,  $r_{ON} = 78m\Omega$
  - $V_{IN} = 2.5V$  时,  $r_{ON} = 93m\Omega$
  - $V_{IN} = 1.8V$  时,  $r_{ON} = 109m\Omega$
  - $V_{IN} = 1.2V$  时,  $r_{ON} = 146m\Omega$
- 500mA 最大持续开关电流
- 静态电流：1.8V 时为 82nA
- 关断电流：1.8V 时为 44nA
- 低控制输入阈值支持使用 1.2V、1.8V、2.5V 和 3.3V 逻辑
- 受控转换率, 可避免浪涌电流
  - $V_{IN} = 1.8V$  时  $t_r = 40\mu s$  (TPS22901/2)
  - $V_{IN} = 1.8V$  时  $t_r = 220\mu s$  (TPS22902B)
- 快速输出放电 (TPS22902/2B)
- ESD 性能测试符合 JESD 22 标准
  - 2000V 人体放电模型{42} (A114-B, II 类)
  - 1000V 充电器件模型 (C101)
- 四引脚晶圆芯片级 DSBGA 封装
  - 0.8mm × 0.8mm, 间距 0.4mm, 高 0.5mm (YFP)

### 2 应用

- 个人数字助理 (PDA)
- 手机
- 全球卫星定位 (GPS) 设备
- MP3 播放器
- 数码照相机
- 外设端口
- 便携式仪表
- 射频模块

### 3 说明

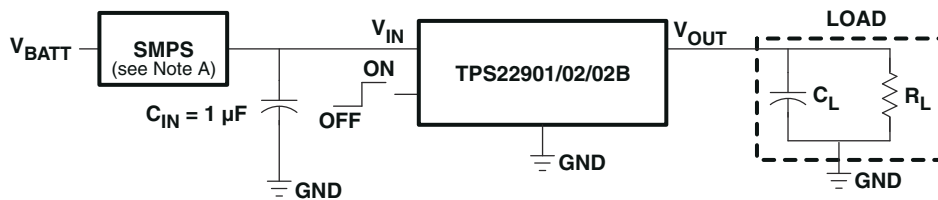
TPS22901、TPS22902 和 TPS22902B 是具有受控开通功能的小型低导通电阻 ( $r_{ON}$ ) 负载开关。这些器件包含一个 P 沟道 MOSFET, 该 MOSFET 可在 1.0V 至 3.6V 的输入电压范围内运行。此开关由一个导通/关断输入 (ON) 控制, 可与低电压控制信号直接连接。在 TPS22902 和 TPS22902B 中添加了一个 88Ω 片上负载电阻器, 用于在开关关闭时进行快速输出放电。

TPS22901、TPS22902 和 TPS22902B 采用节省空间的 0.4mm 间距 4 引脚 DSBGA (YFP) 封装。这些器件在自然通风环境下的额定运行温度范围为 -40°C 至 85°C。

器件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸 (标称值)
TPS22901	DSBGA (4)	0.80mm × 0.80mm
TPS22902		
TPS22902B		

(1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。



A. 开关模式电源

典型应用原理图



## Table of Contents

<b>1 特性</b> .....	<b>1</b>	<b>9 Detailed Description</b> .....	<b>20</b>
<b>2 应用</b> .....	<b>1</b>	9.1 Overview.....	20
<b>3 说明</b> .....	<b>1</b>	9.2 Functional Block Diagram.....	20
<b>4 Revision History</b> .....	<b>2</b>	9.3 Feature Description.....	20
<b>5 Device Comparison Table</b> .....	<b>3</b>	9.4 Device Functional Modes.....	20
<b>6 Pin Configuration and Functions</b> .....	<b>3</b>	<b>10 Application and Implementation</b> .....	<b>21</b>
<b>7 Specifications</b> .....	<b>4</b>	10.1 Application Information.....	21
7.1 Absolute Maximum Ratings.....	4	10.2 Typical Application.....	21
7.2 ESD Ratings.....	4	<b>11 Power Supply Recommendations</b> .....	<b>24</b>
7.3 Recommended Operating Conditions.....	4	<b>12 Layout</b> .....	<b>24</b>
7.4 Thermal Information.....	4	12.1 Layout Guidelines.....	24
7.5 Electrical Characteristics.....	5	12.2 Layout Example.....	24
7.6 Switching Characteristics ( $V_{IN} = 1.1\text{ V}$ ).....	6	<b>13 Device and Documentation Support</b> .....	<b>25</b>
7.7 Switching Characteristics ( $V_{IN} = 1.2\text{ V}$ ).....	6	13.1 Related Links.....	25
7.8 Switching Characteristics ( $V_{IN} = 1.8\text{ V}$ ).....	7	13.2 Trademarks.....	25
7.9 Switching Characteristics ( $V_{IN} = 2.5\text{ V}$ ).....	7	13.3 Electrostatic Discharge Caution.....	25
7.10 Switching Characteristics ( $V_{IN} = 3.0\text{ V}$ ).....	8	13.4 Glossary.....	25
7.11 Switching Characteristics ( $V_{IN} = 3.6\text{ V}$ ).....	8	<b>14 Mechanical, Packaging, and Orderable Information</b> .....	<b>25</b>
7.12 Typical Characteristics.....	9		
<b>8 Parameter Measurement Information</b> .....	<b>19</b>		

## 4 Revision History

注：以前版本的页码可能与当前版本的页码不同

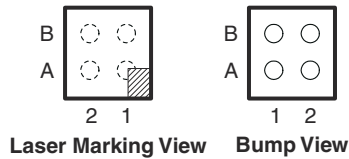
<b>Changes from Revision D (January 2015) to Revision E (September 2020)</b>	<b>Page</b>
• 更新了整个文档的表、图和交叉参考的编号格式。.....	1
<b>Changes from Revision C (December 2012) to Revision D (January 2015)</b>	<b>Page</b>
• 添加了 ESD 等级表、特性说明部分、器件功能模式、应用和实现部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分。.....	1
• Deleted the ORDERING INFORMATION table.....	3
<b>Changes from Revision B (March 2009) to Revision C (December 2012)</b>	<b>Page</b>
• Changed the ORDERING INFORMATION table.....	3

## 5 Device Comparison Table

	R <sub>ON</sub> at 1.8 V (TYP)	RISE TIME (TYP at 1.8 V)	QUICK OUTPUT DISCHARGE <sup>(1)</sup>	MAX OUTPUT CURRENT	ENABLE
TPS22901	109 mΩ	40 μs	No	500 mA	Active high
TPS22902			Yes		
TPS22902B		220 μs	Yes		

(1) This feature discharges the output of the switch to ground through an 88 Ω resistor, preventing the output from floating.

## 6 Pin Configuration and Functions



**图 6-1. YFP Package 4-Pin DSBGA**

### Pin Assignments

<b>B</b>	ON	GND
<b>A</b>	V <sub>IN</sub>	V <sub>OUT</sub>
	<b>2</b>	<b>1</b>

### Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
A1	V <sub>OUT</sub>	O	Switch output
A2	V <sub>IN</sub>	I	Switch input, bypass this input with a ceramic capacitor to ground
B1	GND	-	Ground
B2	ON	I	Switch control input, active high

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>IN</sub>	Input voltage	- 0.3	4	V
V <sub>OUT</sub>	Output voltage		V <sub>IN</sub> + 0.3	V
V <sub>ON</sub>	Input voltage	- 0.3	4	V
P	Power dissipation at T <sub>A</sub> = 25°C		0.48	W
I <sub>MAX</sub>	Maximum continuous switch current		500	mA
T <sub>A</sub>	Operating free-air temperature	- 40	85	°C
T <sub>lead</sub>	Maximum lead temperature (10-s soldering time)		300	°C
T <sub>stg</sub>	Storage temperature	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under [# 7.3](#). Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

		MIN	MAX	UNIT
V <sub>IN</sub>	Input voltage	1	3.6	V
V <sub>OUT</sub>	Output voltage		V <sub>IN</sub>	V
V <sub>IH</sub>	High-level input voltage, ON	0.85	3.6	V
V <sub>IL</sub>	Low-level input voltage, ON		0.4	V
C <sub>IN</sub>	Input capacitor	See <sup>(1)</sup>		μ F

- (1) See [# 10.1.1](#).

### 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS2290X	UNIT
		YFP (DSBGA)	
		4 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	192.1	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	2.3	
R <sub>θJB</sub>	Junction-to-board thermal resistance	35.8	
ψ <sub>JT</sub>	Junction-to-top characterization parameter	11.8	
ψ <sub>JB</sub>	Junction-to-board characterization parameter	35.6	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

$V_{IN} = 1.0\text{ V to }3.6\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted). Typical values are for  $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	$T_A$	MIN	TYP	MAX	UNIT				
$I_Q$	Quiescent current	$I_{OUT} = 0$ , $V_{IN} = V_{ON}$	$V_{IN} = 1.1\text{ V}$	Full	37	120	nA				
			$V_{IN} = 1.8\text{ V}$	Full	82	235					
			$V_{IN} = 3.6\text{ V}$	Full	204	880					
$I_{IN(OFF)}$	OFF-state supply current	$V_{ON} = \text{GND}$ , $V_{OUT} = \text{Open}$	$V_{IN} = 1.1\text{ V}$	Full	22	210	nA				
			$V_{IN} = 1.8\text{ V}$	Full	44	260					
			$V_{IN} = 3.6\text{ V}$	Full	137	700					
$I_{IN(LEAKAGE)}$	OFF-state switch current	$V_{ON} = \text{GND}$ , $V_{OUT} = 0\text{ V}$	$V_{IN} = 1.1\text{ V}$	Full	22	140	nA				
			$V_{IN} = 1.8\text{ V}$	Full	45	230					
			$V_{IN} = 3.6\text{ V}$	Full	137	610					
$r_{ON}$	ON-state resistance	$I_{OUT} = -200\text{ mA}$	$V_{IN} = 3.6\text{ V}$	$25^\circ\text{C}$	78	95	m $\Omega$				
				Full		95					
			$V_{IN} = 2.5\text{ V}$	$25^\circ\text{C}$	93	110					
				Full		110					
			$V_{IN} = 1.8\text{ V}$	$25^\circ\text{C}$	109	130					
				Full		130					
			$V_{IN} = 1.2\text{ V}$	$25^\circ\text{C}$	146	200					
				Full		200					
			$V_{IN} = 1.1\text{ V}$	$25^\circ\text{C}$	174	330					
				Full		330					
			$r_{PD}$	Output pulldown resistance	$V_{IN} = 3.3\text{ V}$ , $V_{ON} = 0$ , $I_{OUT} = 30\text{ mA}$ (TPS22902/TPS22902B only)	$25^\circ\text{C}$			88	120	$\Omega$
			$I_{ON}$	ON input leakage current	$V_{ON} = 1.1\text{ V to }3.6\text{ V or GND}$	Full				25	nA

## 7.6 Switching Characteristics ( $V_{IN} = 1.1\text{ V}$ )

$V_{IN} = 1.1\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$t_{ON}$ Turn-ON time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	108			108			531			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	131			131			596			
		$C_L = 3.3\ \mu\text{F}$	153			153			659			
$t_{OFF}$ Turn-OFF time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	39			11			11			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	317			69			67			
		$C_L = 3.3\ \mu\text{F}$	1105			238			225			
$t_r$ $V_{OUT}$ rise time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	70			70			365			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	78			78			367			
		$C_L = 3.3\ \mu\text{F}$	92			92			395			
$t_f$ $V_{OUT}$ fall time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	107			18			21			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	966			175			189			
		$C_L = 3.3\ \mu\text{F}$	3532			632			565			

(1) Quick Output Discharge

## 7.7 Switching Characteristics ( $V_{IN} = 1.2\text{ V}$ )

$V_{IN} = 1.2\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$t_{ON}$ Turn-ON time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	96			96			471			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	116			116			527			
		$C_L = 3.3\ \mu\text{F}$	135			135			587			
$t_{OFF}$ Turn-OFF time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	39			10			10			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	317			62			61			
		$C_L = 3.3\ \mu\text{F}$	1110			210			199			
$t_r$ $V_{OUT}$ rise time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	62			62			324			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	69			69			325			
		$C_L = 3.3\ \mu\text{F}$	81			81			350			
$t_f$ $V_{OUT}$ fall time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	109			17			20			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	995			163			175			
		$C_L = 3.3\ \mu\text{F}$	3650			587			523			

(1) Quick Output Discharge

## 7.8 Switching Characteristics ( $V_{IN} = 1.8\text{ V}$ )

 $V_{IN} = 1.8\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$t_{ON}$ Turn-ON time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	61			61			302			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	72			72			335			
		$C_L = 3.3\ \mu\text{F}$	83			83			367			
$t_{OFF}$ Turn-OFF time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	38			8			8			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	317			49			49			
		$C_L = 3.3\ \mu\text{F}$	1135			169			167			
$t_r$ $V_{OUT}$ rise time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	40			40			220			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	45			45			220			
		$C_L = 3.3\ \mu\text{F}$	53			53			235			
$t_f$ $V_{OUT}$ fall time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	111			15			15			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	1020			140			159			
		$C_L = 3.3\ \mu\text{F}$	3700			517			481			

(1) Quick Output Discharge

## 7.9 Switching Characteristics ( $V_{IN} = 2.5\text{ V}$ )

 $V_{IN} = 2.5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$t_{ON}$ Turn-ON time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	45			45			223			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	53			53			246			
		$C_L = 3.3\ \mu\text{F}$	61			61			268			
$t_{OFF}$ Turn-OFF time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	38			7			7			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	314			46			47			
		$C_L = 3.3\ \mu\text{F}$	1140			161			158			
$t_r$ $V_{OUT}$ rise time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	32			32			175			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	35			35			175			
		$C_L = 3.3\ \mu\text{F}$	41			41			187			
$t_f$ $V_{OUT}$ fall time	$R_L = 500\ \Omega$	$C_L = 0.1\ \mu\text{F}$	113			14			18			$\mu\text{s}$
		$C_L = 1\ \mu\text{F}$	1040			139			185			
		$C_L = 3.3\ \mu\text{F}$	3795			516			471			

(1) Quick Output Discharge

### 7.10 Switching Characteristics (V<sub>IN</sub> = 3.0 V)

V<sub>IN</sub> = 3.0 V, T<sub>A</sub> = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t <sub>ON</sub> Turn-ON time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	38			38			191			μs
		C <sub>L</sub> = 1 μF	45			45			211			
		C <sub>L</sub> = 3.3 μF	53			53			231			
t <sub>OFF</sub> Turn-OFF time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	38			7			7			μs
		C <sub>L</sub> = 1 μF	320			46			46			
		C <sub>L</sub> = 3.3 μF	1145			53			156			
t <sub>r</sub> V <sub>OUT</sub> rise time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	28			28			159			μs
		C <sub>L</sub> = 1 μF	31			31			160			
		C <sub>L</sub> = 3.3 μF	37			37			170			
t <sub>f</sub> V <sub>OUT</sub> fall time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	114			14			17			μs
		C <sub>L</sub> = 1 μF	1045			139			160			
		C <sub>L</sub> = 3.3 μF	3815			509			473			

(1) Quick Output Discharge

### 7.11 Switching Characteristics (V<sub>IN</sub> = 3.6 V)

V<sub>IN</sub> = 3.6 V, T<sub>A</sub> = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TPS22901			TPS22902 <sup>(1)</sup>			TPS22902B <sup>(1)</sup>			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t <sub>ON</sub> Turn-ON time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	33			33			166			μs
		C <sub>L</sub> = 1 μF	39			39			183			
		C <sub>L</sub> = 3.3 μF	46			46			201			
t <sub>OFF</sub> Turn-OFF time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	38			7			7			μs
		C <sub>L</sub> = 1 μF	322			46			45			
		C <sub>L</sub> = 3.3 μF	1145			156			155			
t <sub>r</sub> V <sub>OUT</sub> rise time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	25			25			146			μs
		C <sub>L</sub> = 1 μF	28			28			146			
		C <sub>L</sub> = 3.3 μF	34			34			156			
t <sub>f</sub> V <sub>OUT</sub> fall time	R <sub>L</sub> = 500 Ω	C <sub>L</sub> = 0.1 μF	116			14			17			μs
		C <sub>L</sub> = 1 μF	1060			139			161			
		C <sub>L</sub> = 3.3 μF	3840			512			475			

(1) Quick Output Discharge



## 7.12 Typical Characteristics

### 7.12.1 Typical DC Characteristics

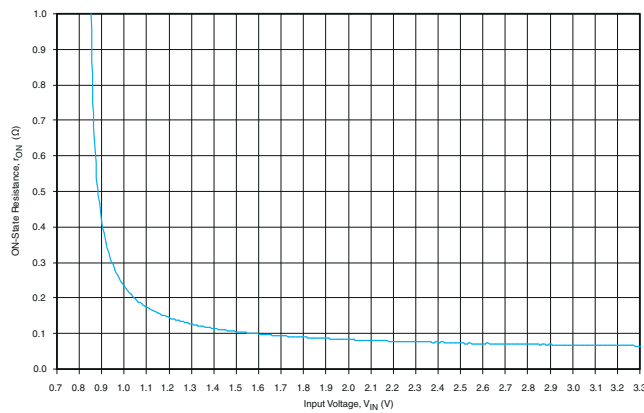


图 7-1.  $r_{ON}$  vs  $V_{IN}$

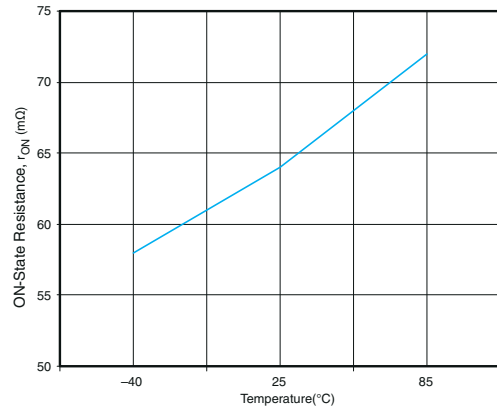


图 7-2.  $r_{ON}$  vs Temperature ( $V_{IN} = 3.3$  V)

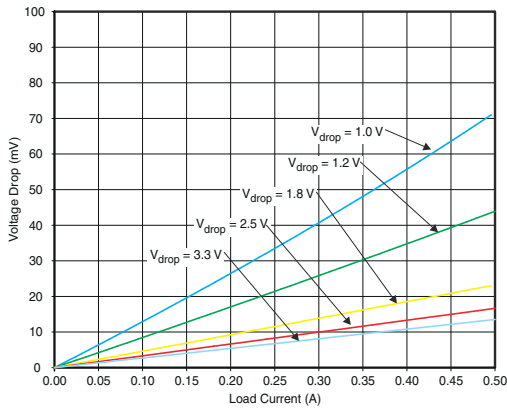


图 7-3. Voltage Drop vs. Load Current

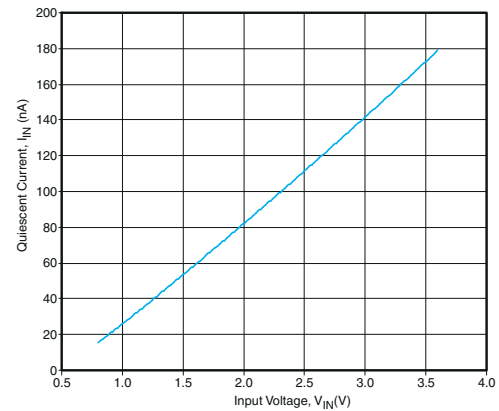


图 7-4. Quiescent Current vs  $V_{IN}$  ( $V_{ON} = V_{IN}$ ,  $I_{OUT} = 0$ )

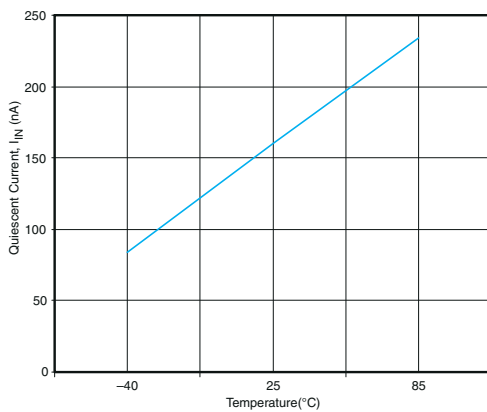


图 7-5. Quiescent Current vs Temperature ( $V_{IN} = 3.3$  V,  $I_{OUT} = 0$ )

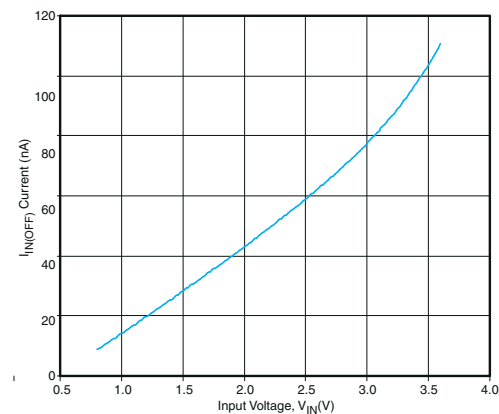


图 7-6.  $I_{IN(OFF)}$  vs  $V_{IN}$  ( $V_{ON} = 0$  V)

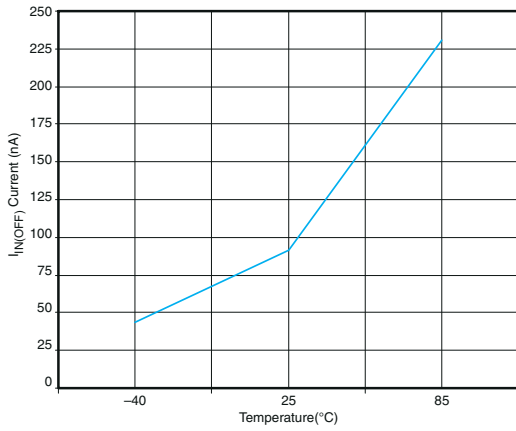


图 7-7.  $I_{IN(OFF)}$  vs Temperature ( $V_{IN} = 3.3$  V)

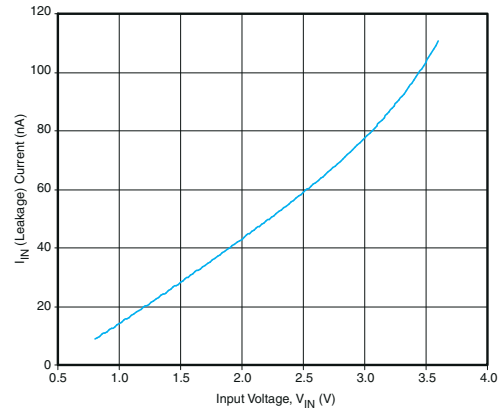


图 7-8.  $I_{IN}$  (Leakage) vs  $V_{IN}$  ( $I_{OUT} = 0$ )

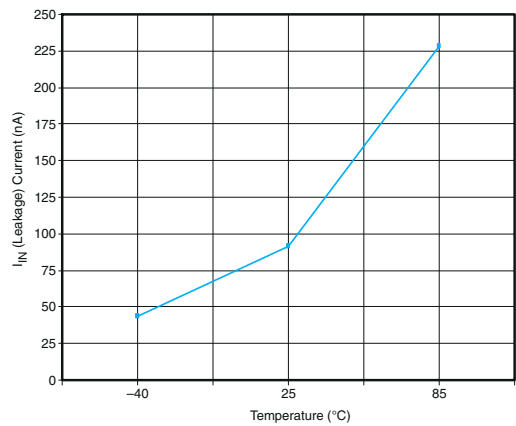


图 7-9.  $I_{IN}$  (Leakage) vs Temperature ( $V_{IN} = 3.3$  V)

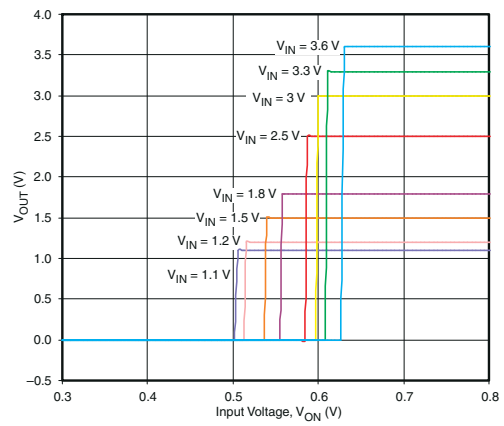
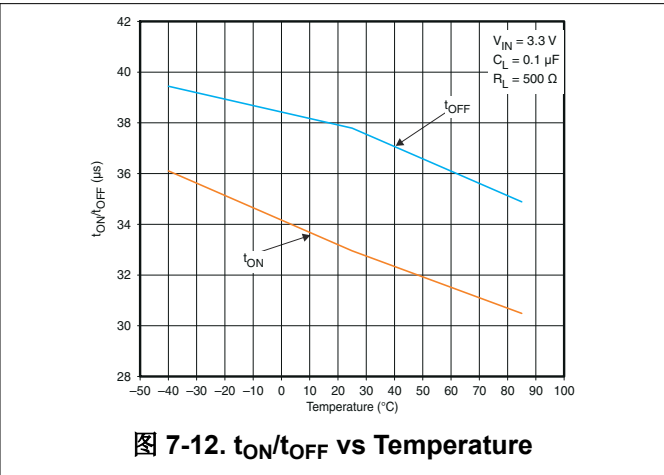
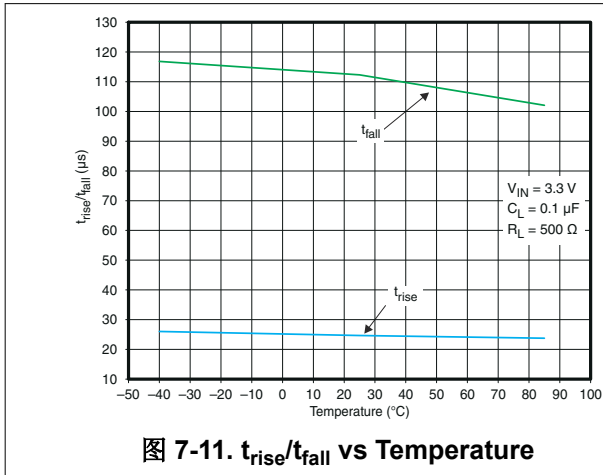


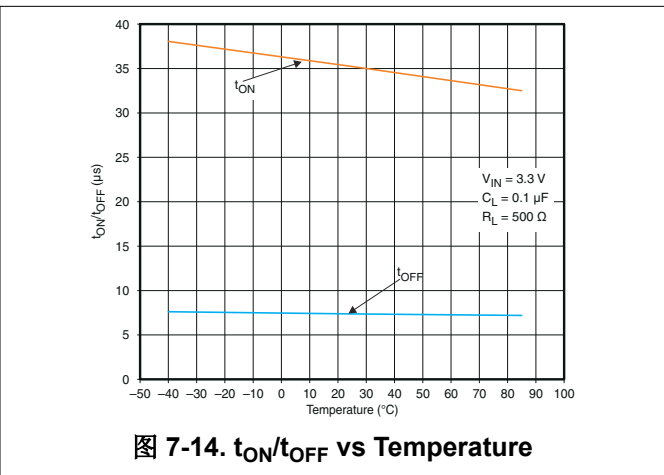
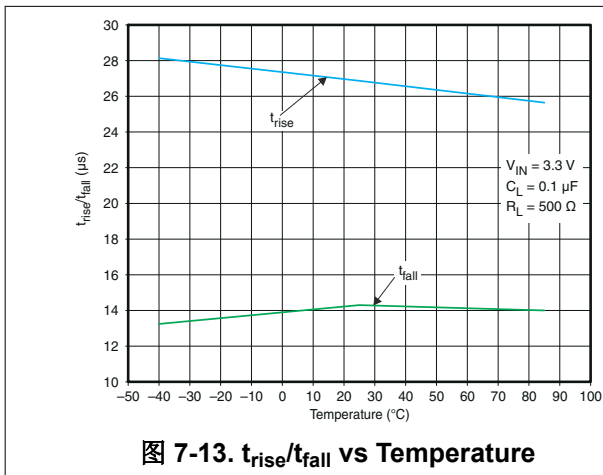
图 7-10. ON-Input Threshold

## 7.12.2 Typical AC Characteristics

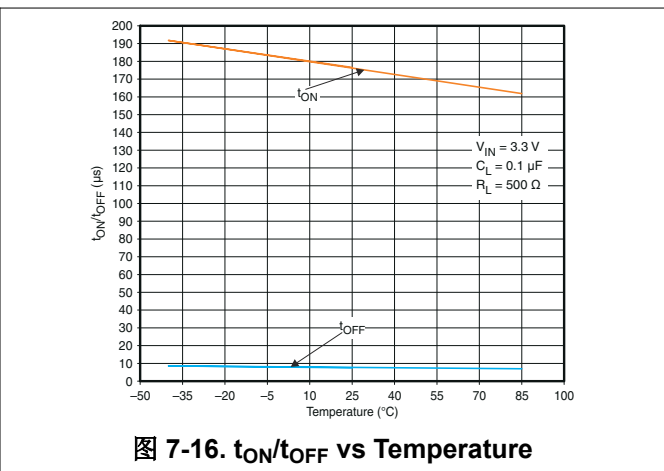
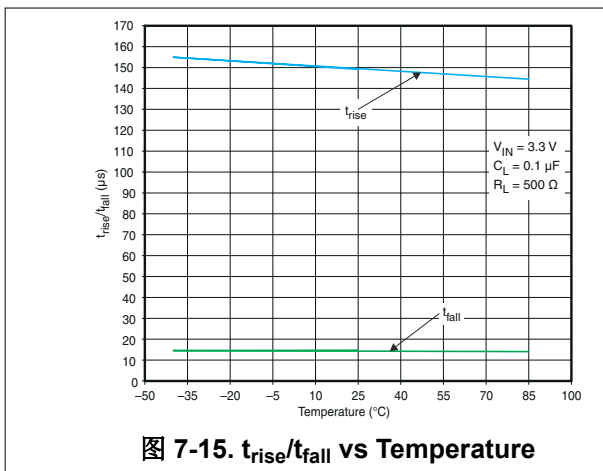
### 7.12.2.1 TPS22901



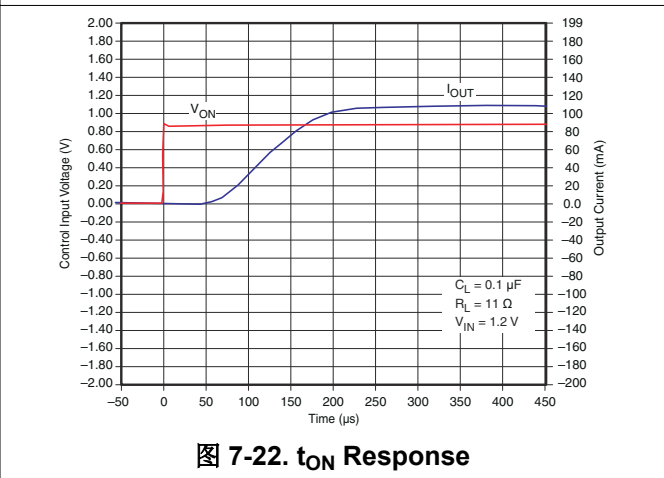
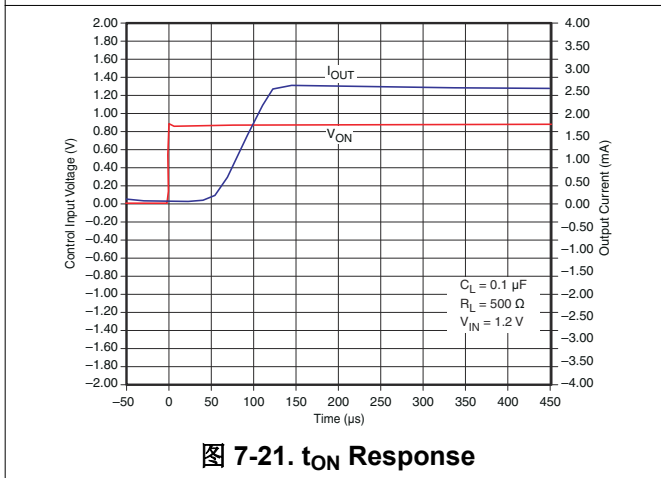
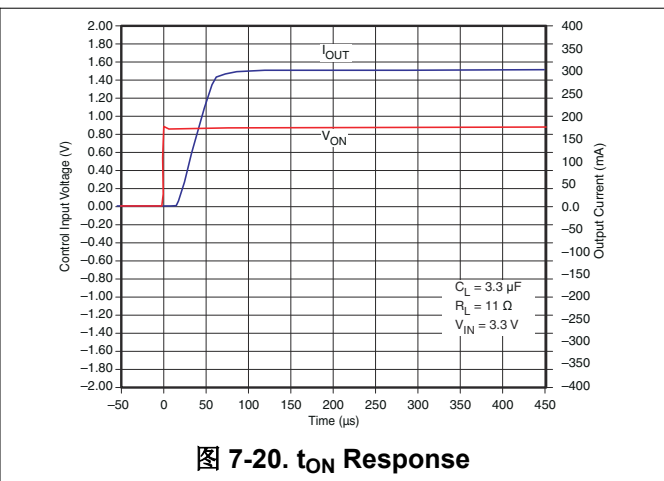
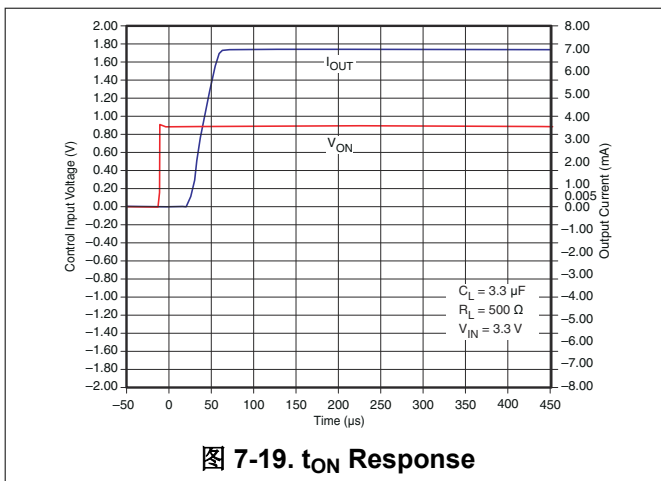
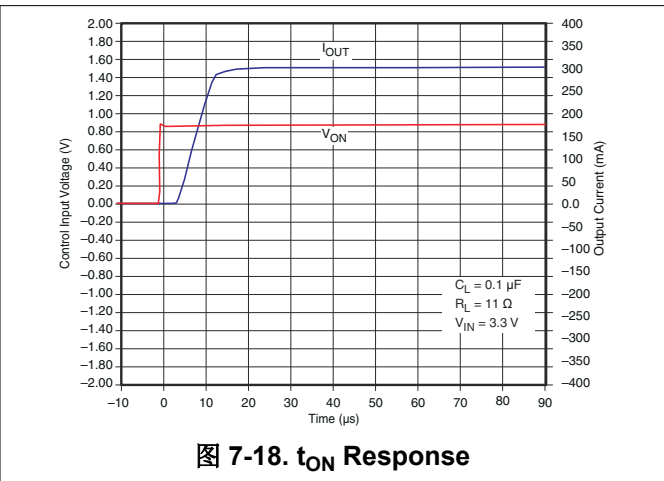
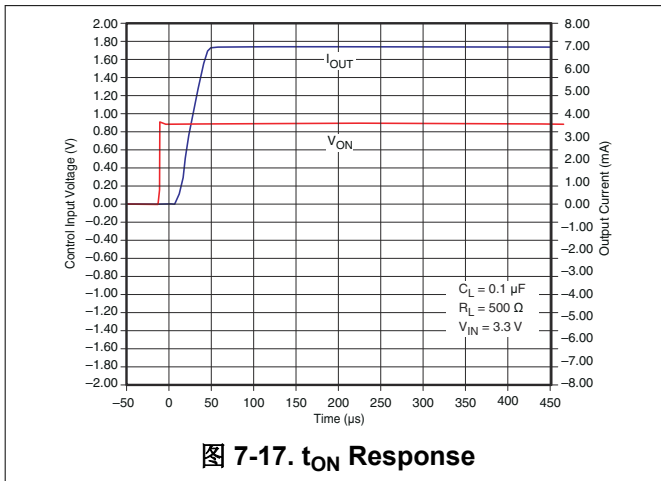
### 7.12.2.2 TPS22902

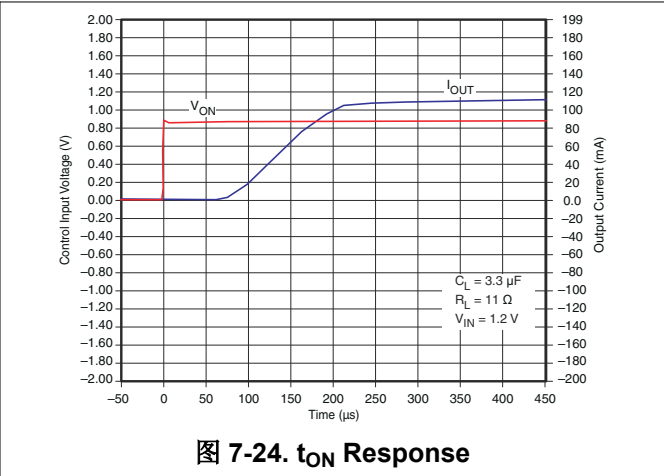
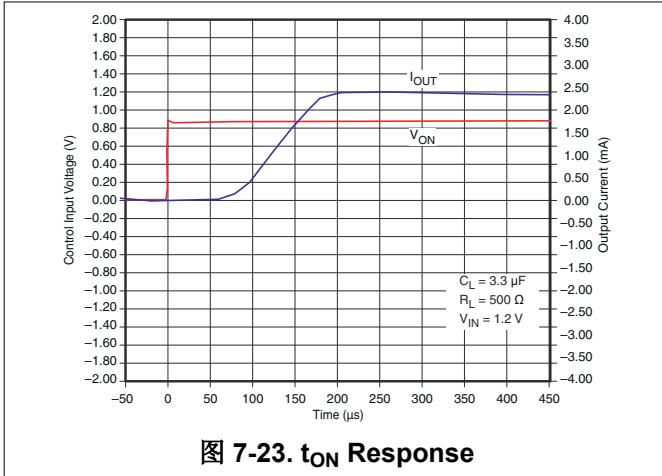


### 7.12.2.3 TPS22902B

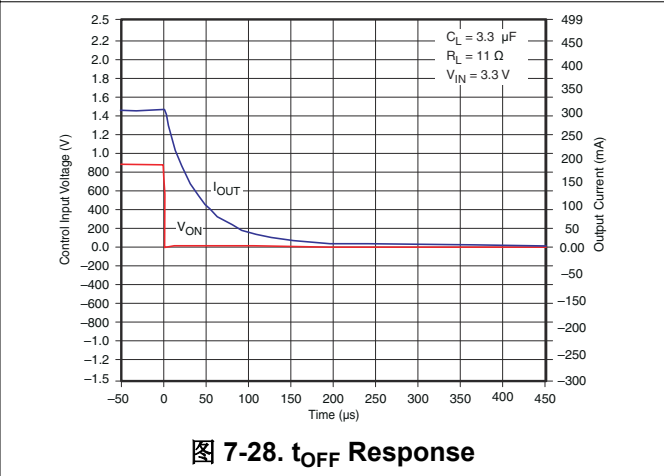
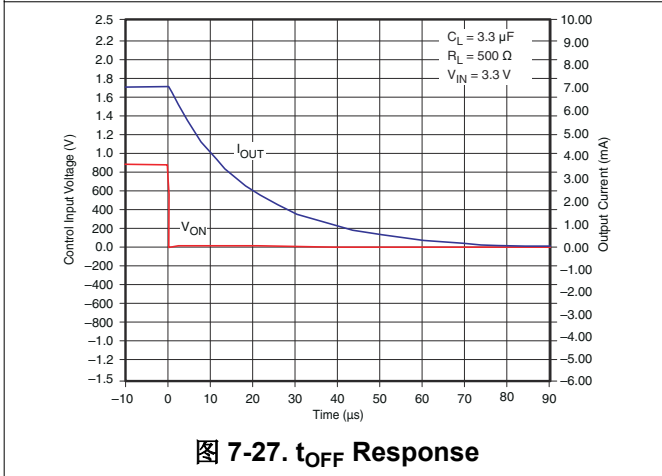
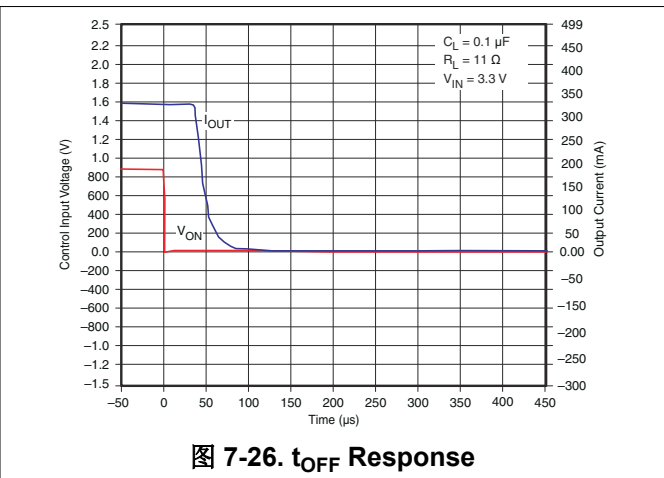
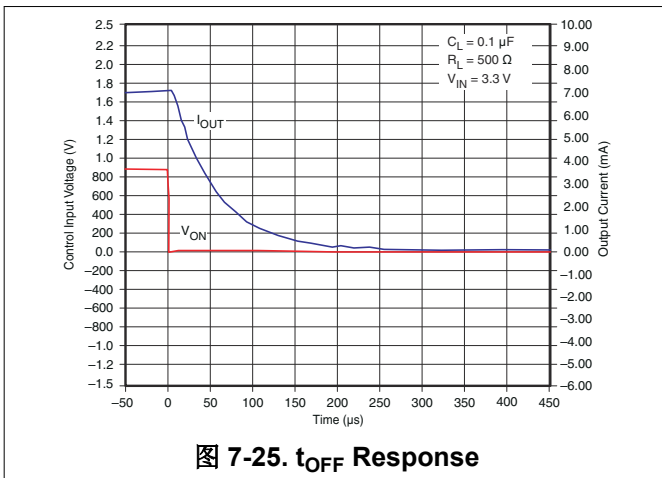


7.12.2.4 TPS22901 and TPS22902





7.12.2.5 TPS22901



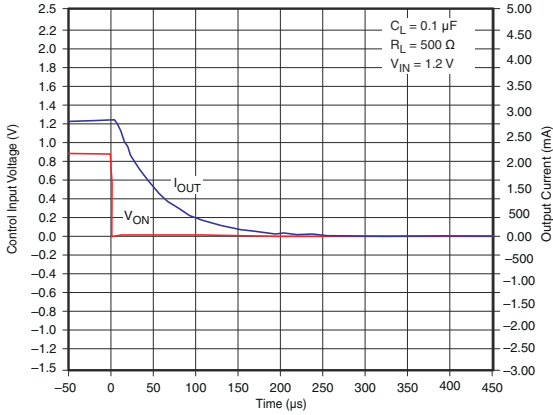


图 7-29.  $t_{OFF}$  Response

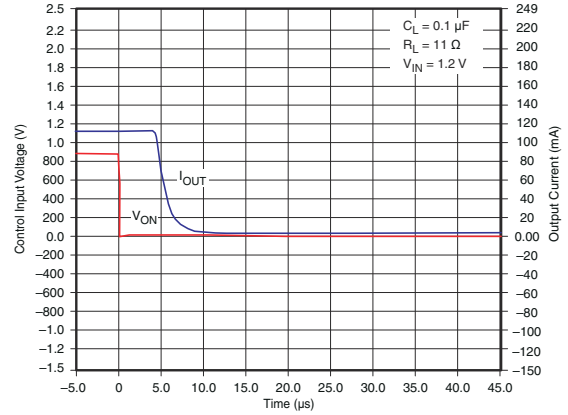


图 7-30.  $t_{OFF}$  Response

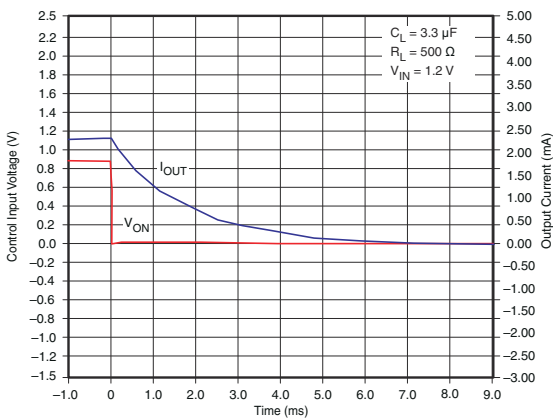


图 7-31.  $t_{OFF}$  Response

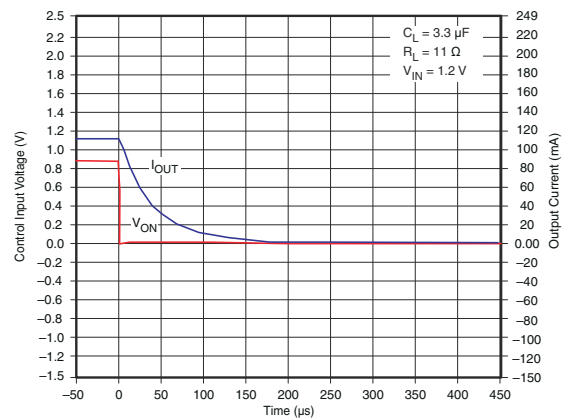


图 7-32.  $t_{OFF}$  Response

### 7.12.2.6 TPS22902

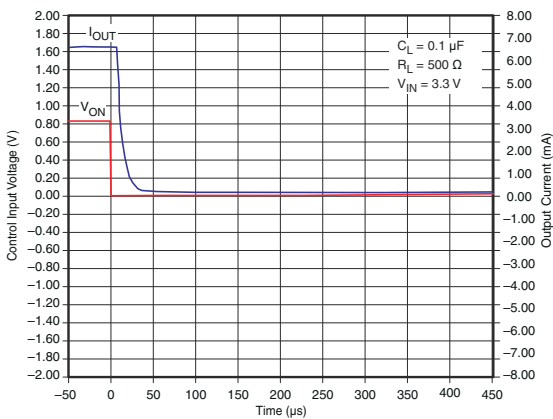


图 7-33.  $t_{OFF}$  Response

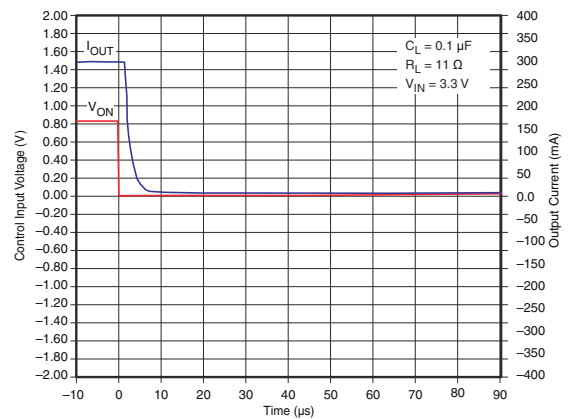
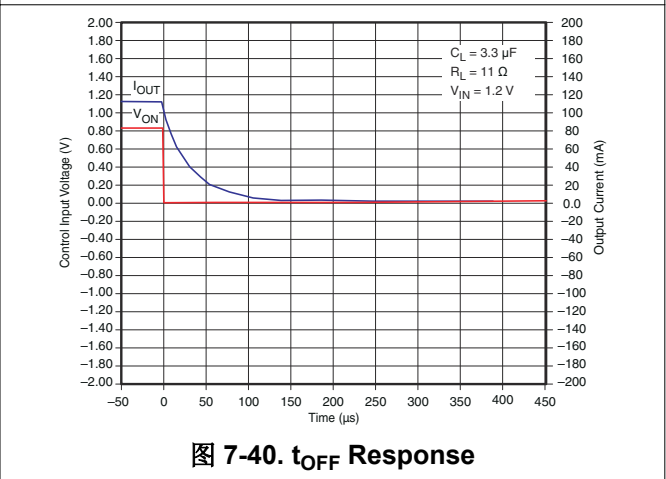
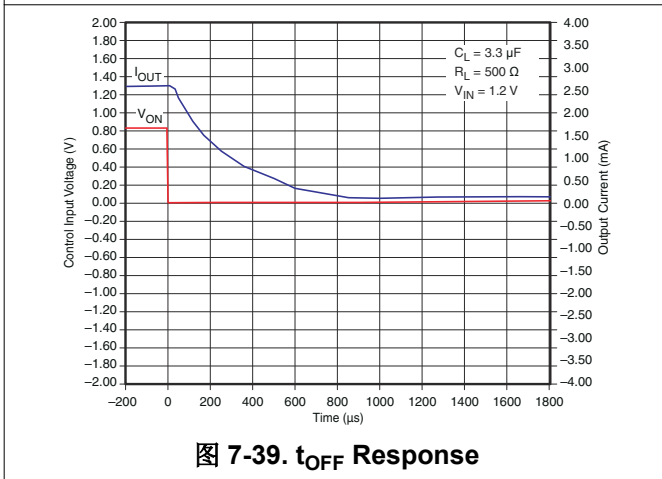
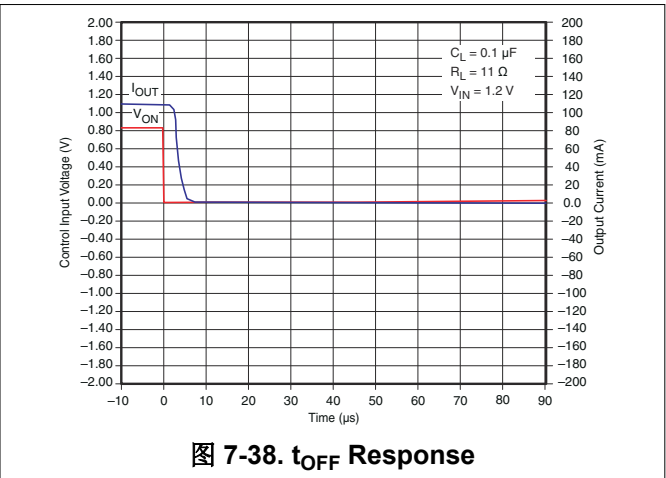
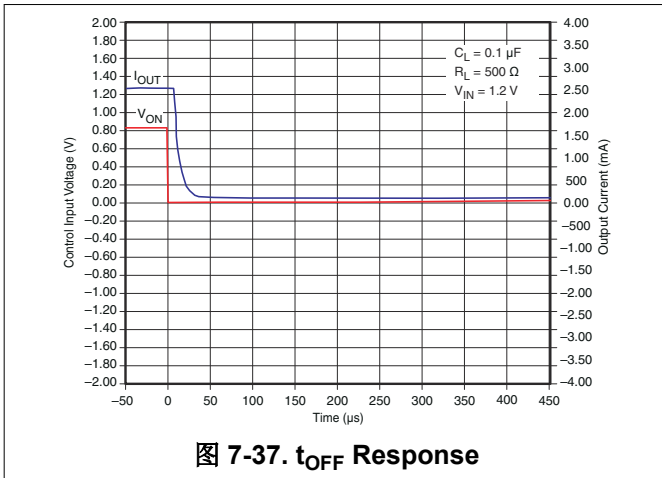
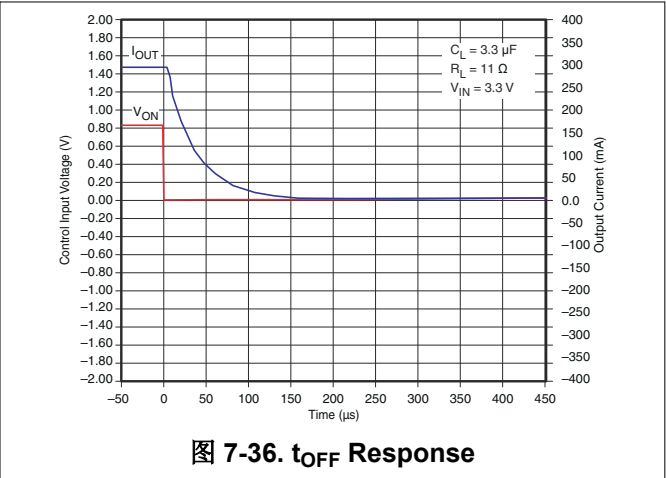
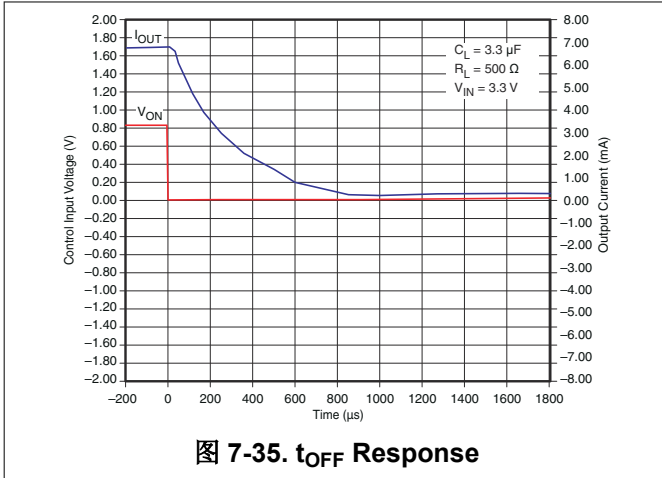
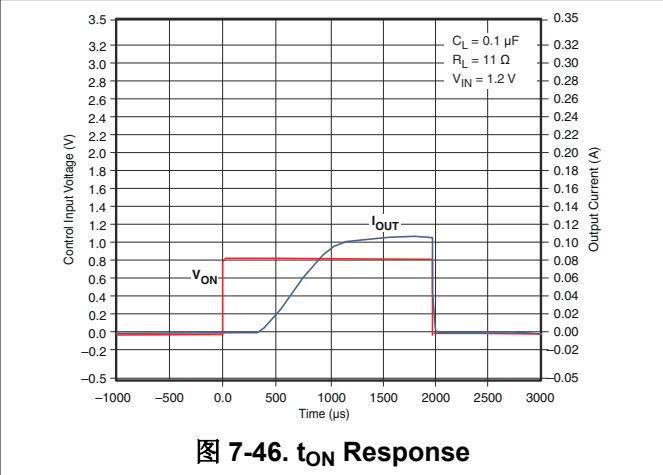
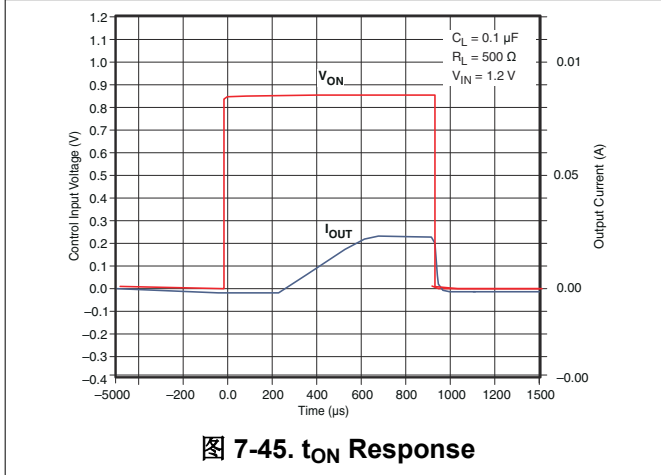
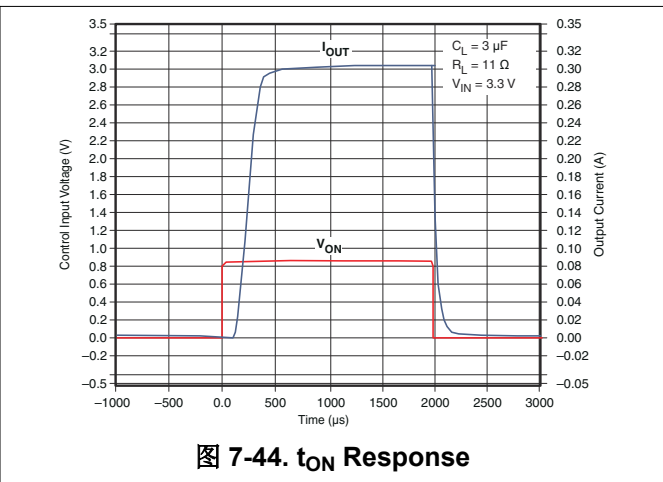
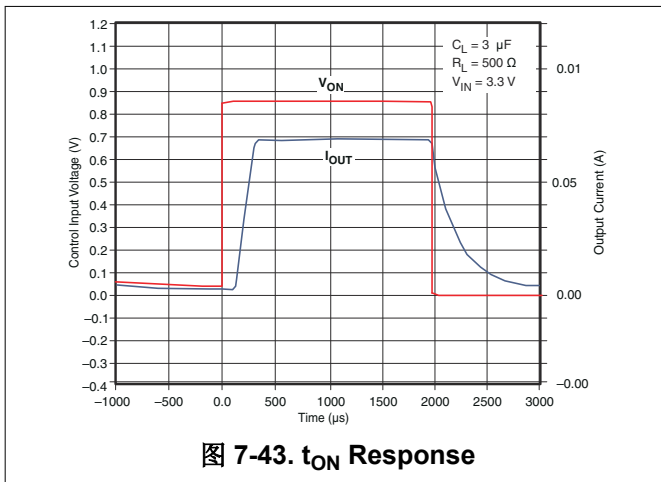
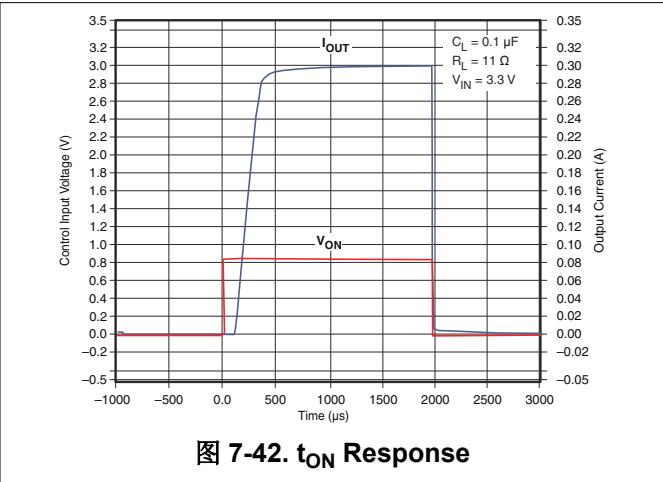
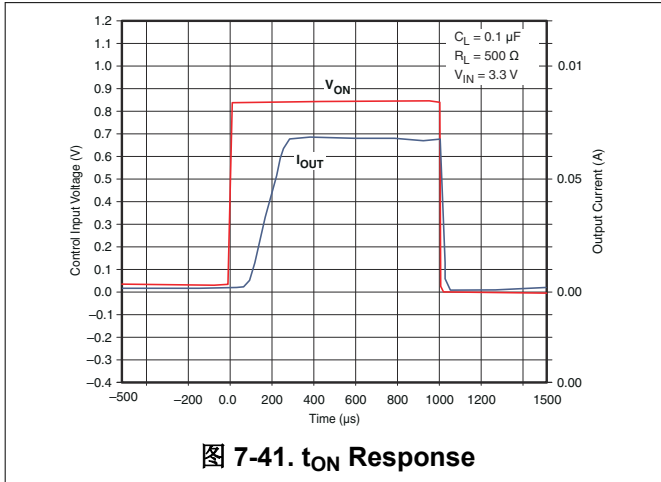


图 7-34.  $t_{OFF}$  Response



7.12.2.7 TPS22902B





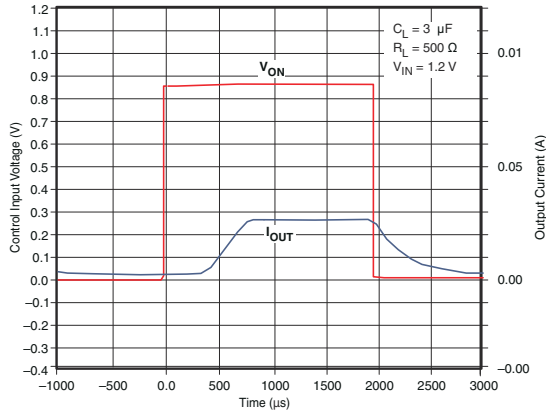


图 7-47.  $t_{ON}$  Response

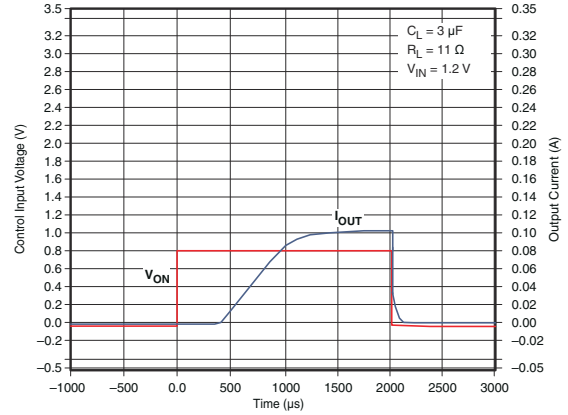


图 7-48.  $t_{ON}$  Response

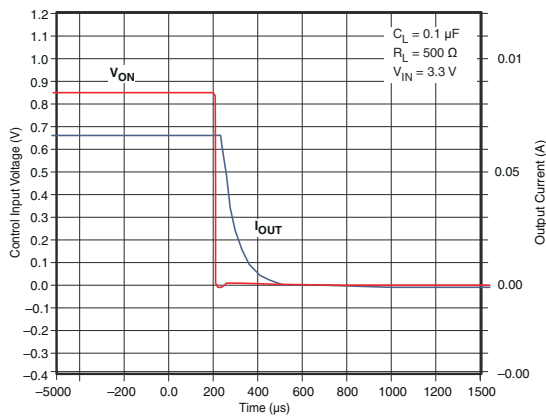


图 7-49.  $t_{OFF}$  Response

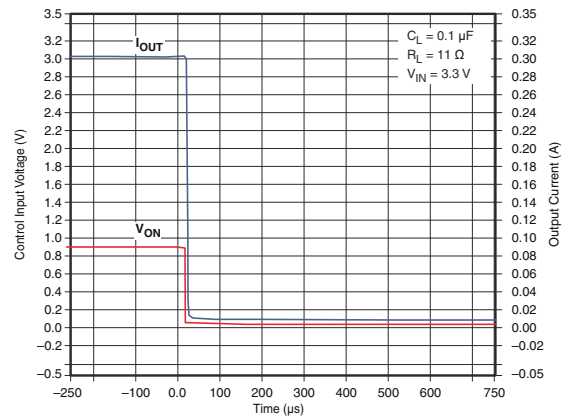


图 7-50.  $t_{OFF}$  Response

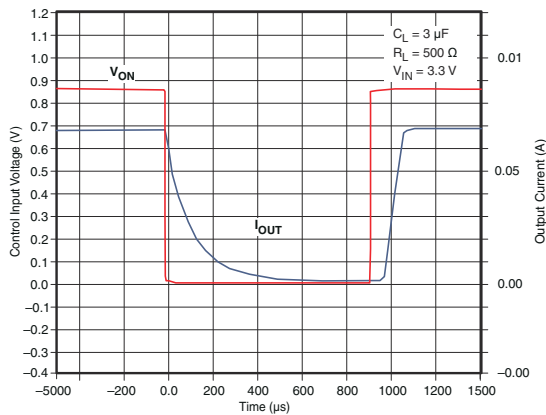


图 7-51.  $t_{OFF}$  Response

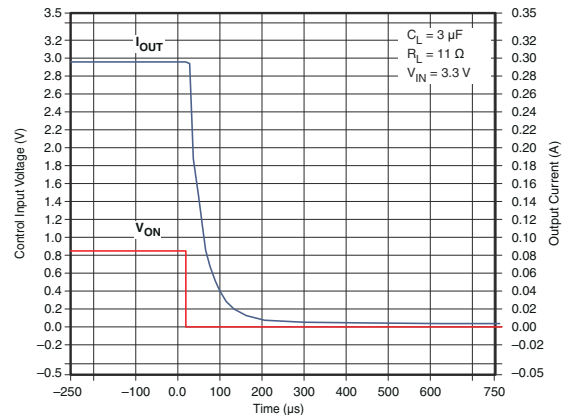


图 7-52.  $t_{OFF}$  Response

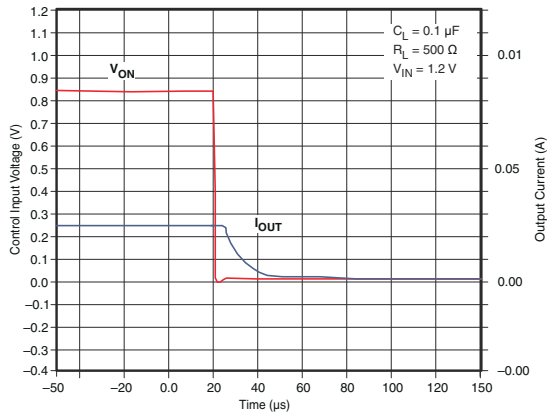


图 7-53.  $t_{OFF}$  Response

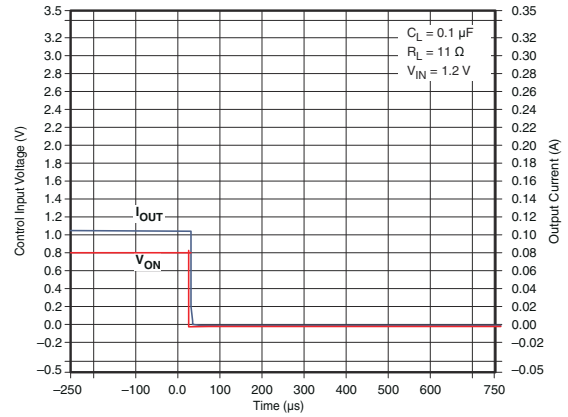


图 7-54.  $t_{OFF}$  Response

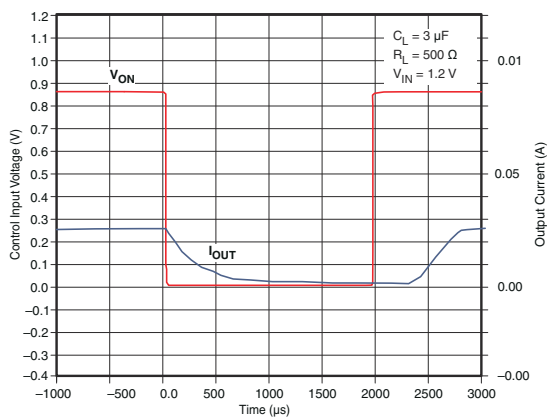


图 7-55.  $t_{OFF}$  Response

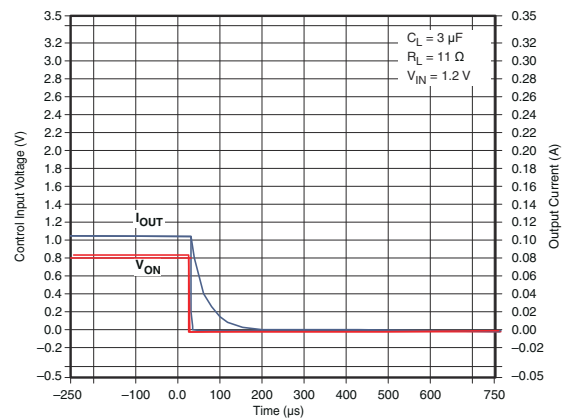
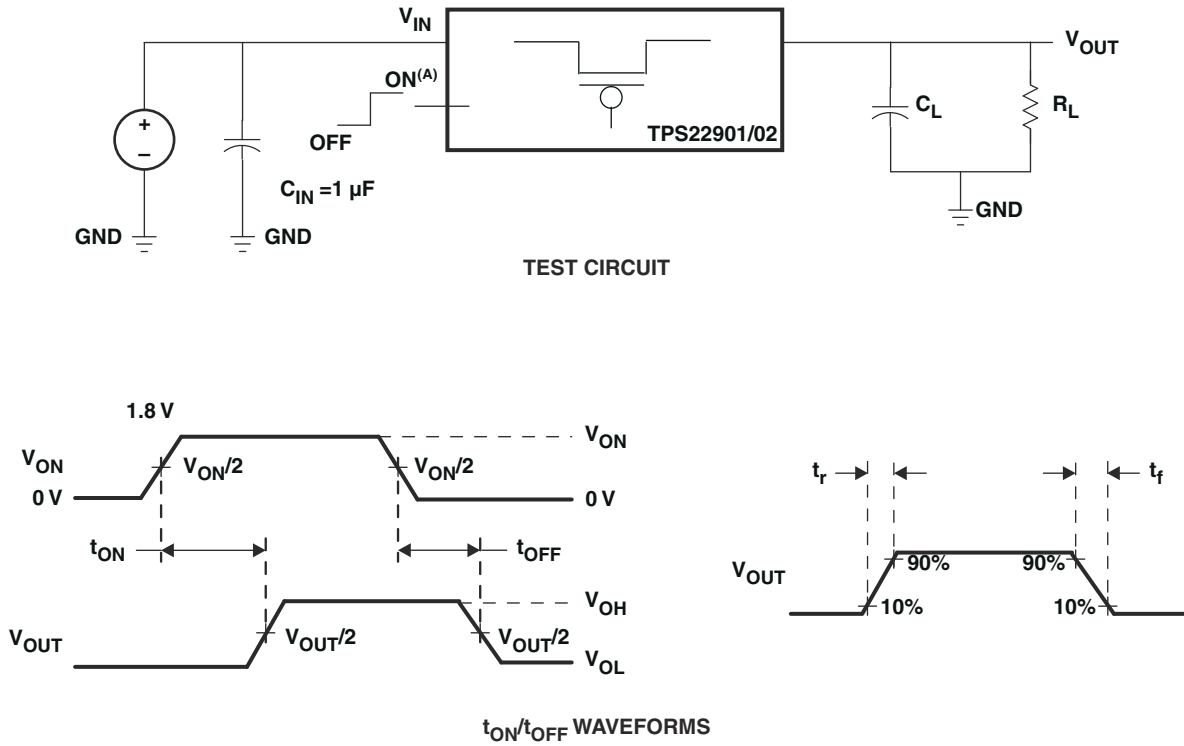


图 7-56.  $t_{OFF}$  Response

## 8 Parameter Measurement Information



A.  $t_{rise}$  and  $t_{fall}$  of the control signal is 100 ns.

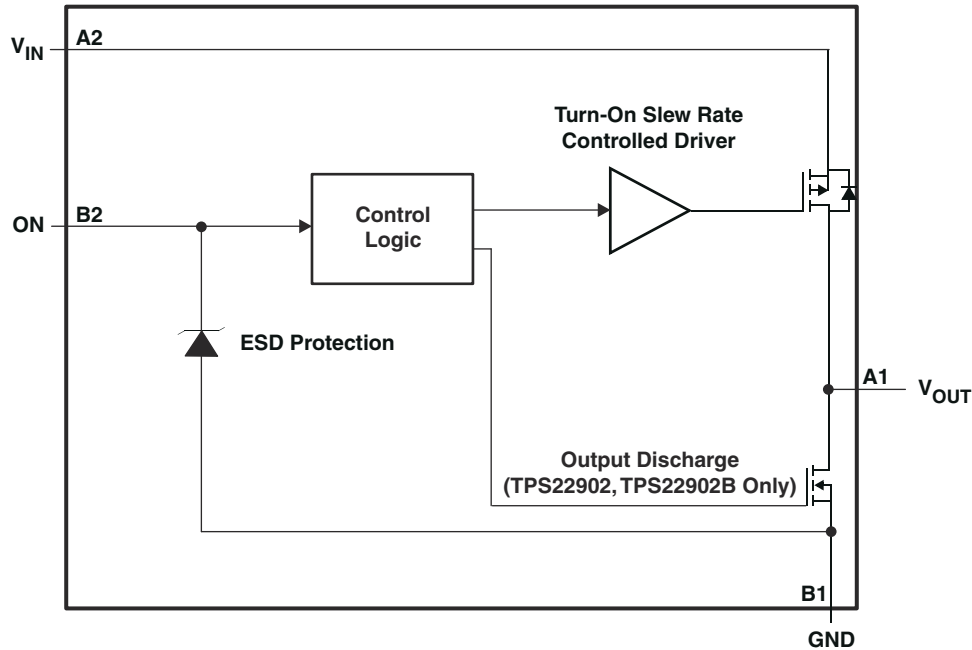
**图 8-1. Test Circuit and  $t_{ON}/t_{OFF}$  Waveforms**

## 9 Detailed Description

### 9.1 Overview

The TPS2290x and TPS22902B is a single channel, 500-mA load switch in a small, space-saving DSBGA-4 package. These devices implement a P-channel MOSFET to provide a low ON-resistance for a low voltage drop across the device. A controlled rise time is used in applications to limit the inrush current.

### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 ON/OFF Control

The ON pin controls the state of the switch. Activating ON continuously holds the switch in the on state. ON is active-high and has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic threshold, and it can be used with any microcontroller with 1.2 V, 1.8 V, 2.5 V or 3.3 V GPIOs.

#### 9.3.2 Quick Output Discharge

The TPS2290x and TPS22902B includes the Quick Output Discharge (QOD) feature. When the switch is disabled, a discharge resistance with a typical value of 88  $\Omega$  is connected between the output and ground. This resistance pulls down the output and prevents it from floating when the device is disabled.

### 9.4 Device Functional Modes

表 9-1 lists the VOUT pin connections for a particular device as determined by the ON pin.

**Table 9-1. VOUT Function Table**

ON (Control Input)	TPS22901	TPS22902/2B
L	Open	GND
H	VIN	VIN

## 10 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

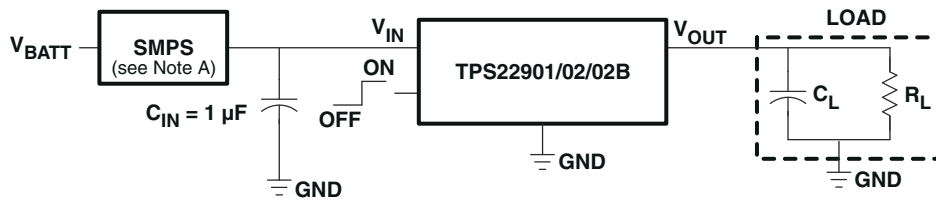
#### 10.1.1 Input Capacitor (Optional)

To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor, a capacitor needs to be placed between  $V_{IN}$  and GND. A 1- $\mu$ F ceramic capacitor,  $C_{IN}$ , placed close to the pins is usually sufficient. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop during high current application. When switching heavy loads, TI recommends using an input capacitor about 10 times higher than the output capacitor in order to avoid excessive voltage drop.

#### 10.1.2 Output Capacitor (Optional)

Because of the integral body diode in the PMOS switch, a  $C_{IN}$  greater than  $C_L$  is highly recommended. A  $C_L$  greater than  $C_{IN}$  can cause  $V_{OUT}$  to exceed  $V_{IN}$  when the system supply is removed. This could result in current flow through the body diode from  $V_{OUT}$  to  $V_{IN}$ .

### 10.2 Typical Application



A. Switched-mode power supply

图 10-1. Typical Application Schematic

#### 10.2.1 Design Requirements

Table 10-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
$V_{IN}$	1.8 V
$C_L$	4.7 $\mu$ F
Load current	500 mA
Ambient Temperature	25 $^{\circ}$ C
Maximum inrush current	200 mA

## 10.2.2 Detailed Design Procedure

### 10.2.2.1 Managing Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0 V to the set value (1.8 V in this example). This charge arrives in the form of inrush current. Inrush current can be calculated using the following equation:

$$I_{\text{INRUSH}} = C_L \times \frac{dV_{\text{OUT}}}{dt} \quad (1)$$

where:

- $C_L$  = Output capacitance
- $dV_{\text{OUT}}$  = Output voltage
- $dt$  = Rise time

The TPS2290x and TPS22902B offers a controlled rise time for minimizing inrush current. This device can be selected based upon the minimum acceptable rise time which can be calculated using the design requirements and the inrush current equation. An output capacitance of 4.7  $\mu\text{F}$  will be used since the amount of inrush current increases with output capacitance:

$$\begin{aligned} 200 \text{ mA} &= 4.7 \mu\text{F} \times 1.8\text{V} / dt \\ dt &= 42.3 \mu\text{s} \end{aligned} \quad (2)$$

To ensure an inrush current of less than 200 mA, a device with a rise time greater than 42.3  $\mu\text{s}$  must be used. The TPS22902B has a typical rise time of 220  $\mu\text{s}$  at 1.8 V which meets the above design requirements. The TPS22901/2 has a faster rise time of 40  $\mu\text{s}$  at 1.8 V, and this would result in an inrush current larger than desired.

### 10.2.2.2 VIN to VOUT Voltage Drop

The voltage drop from VIN to VOUT is determined by the ON-resistance of the device and the load current.  $R_{\text{ON}}$  can be found in [# 7.5](#) and is dependent on temperature. When the value of  $R_{\text{ON}}$  is found, the following equation can be used to calculate the voltage drop across the device:

$$\Delta V = I_{\text{LOAD}} \times R_{\text{ON}} \quad (3)$$

where:

- $\Delta V$  = Voltage drop across the device
- $I_{\text{LOAD}}$  = Load current
- $R_{\text{ON}}$  = ON-resistance of the device

At  $V_{\text{IN}} = 1.8 \text{ V}$ , the TPS22901/2/2B has an  $R_{\text{ON}}$  value of 109 m $\Omega$ . Using this value and the defined load current, the above equation can be evaluated:

$$\begin{aligned} \Delta V &= 500 \text{ mA} \times 109 \text{ m}\Omega \\ \Delta V &= 54.5 \text{ mV} \end{aligned} \quad (4)$$

Therefore, the voltage drop across the device will be 54.5 mV.

### 10.2.3 Application Curve

图 10-2 shows the expected voltage drop across the device for different load currents and input voltages.

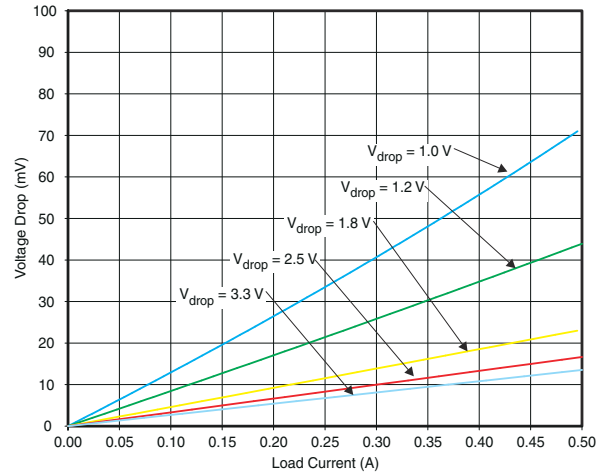


图 10-2. Voltage Drop vs Load Current

## 11 Power Supply Recommendations

The device is designed to operate with a  $V_{IN}$  range of 1 V to 3.6 V. This supply must be well regulated and placed as close to the device terminals as possible. It must also be able to withstand all transient and load currents, using a recommended input capacitance of 1  $\mu\text{F}$  if necessary. If the supply is located more than a few inches from the device terminals, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. If additional bulk capacitance is required, an electrolytic, tantalum, or ceramic capacitor of 10  $\mu\text{F}$  may be sufficient.

## 12 Layout

### 12.1 Layout Guidelines

For best performance,  $V_{IN}$ ,  $V_{OUT}$ , and GND traces should be as short and wide as possible to help minimize the parasitic electrical effects. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal operation.

For higher reliability, the maximum IC junction temperature,  $T_{J(\text{max})}$ , should be restricted to 125°C under normal operating conditions. Junction temperature is directly proportional to power dissipation in the device and the two are related by

$$T_J = T_A + \theta_{JA} \times P_D \quad (5)$$

where:

- $T_J$  = Junction temperature of the device
- $T_A$  = Ambient temperature
- $P_D$  = Power dissipation inside the device
- $\theta_{JA}$  = Junction to ambient thermal resistance. See Thermal Information section of the datasheet. This parameter is highly dependent on board layout.

### 12.2 Layout Example

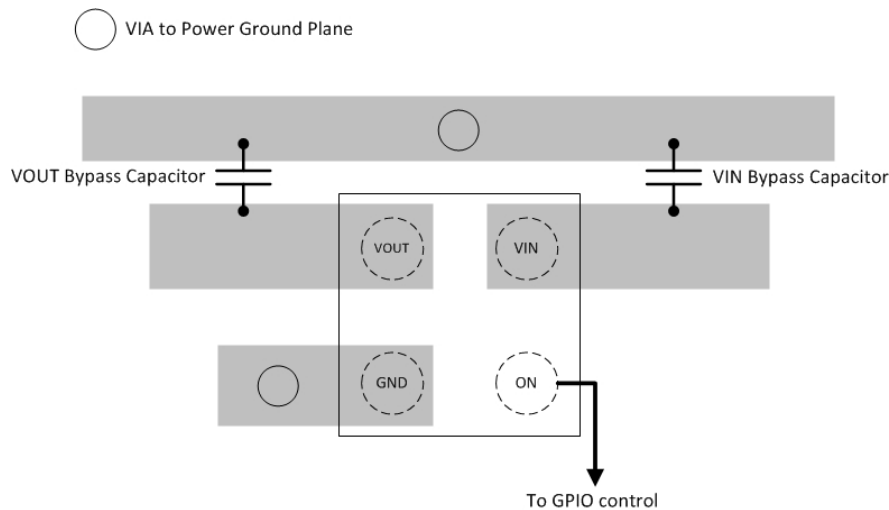


图 12-1. Layout Example Schematic



## 13 Device and Documentation Support

### 13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 13-1. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS22901	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TPS22902	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TPS22902B	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 13.2 Trademarks

所有商标均为其各自所有者的财产。

### 13.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 13.4 Glossary

**TI Glossary** This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS22901YFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	3P (3, 5)	<a href="#">Samples</a>
TPS22902BYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	3S 3	<a href="#">Samples</a>
TPS22902YFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	3R	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

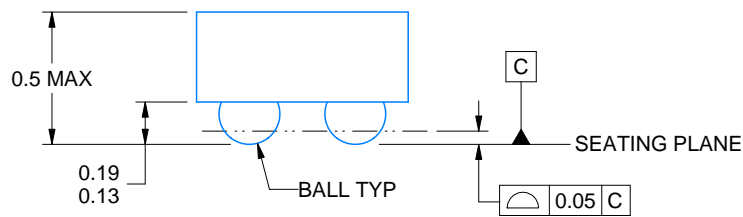
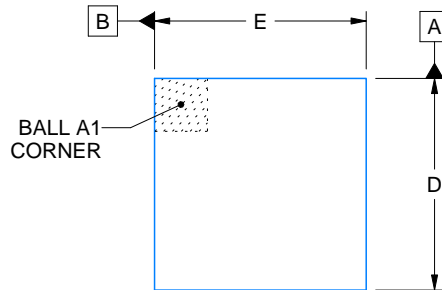
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22901YFPR	DSBGA	YFP	4	3000	178.0	9.2	0.89	0.89	0.58	4.0	8.0	Q1
TPS22902BYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.89	0.89	0.58	4.0	8.0	Q1
TPS22902YFPR	DSBGA	YFP	4	3000	180.0	8.4	0.89	0.89	0.58	4.0	8.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22901YFPR	DSBGA	YFP	4	3000	220.0	220.0	35.0
TPS22902BYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22902YFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0



D: Max = 0.79 mm, Min = 0.73 mm  
 E: Max = 0.79 mm, Min = 0.73 mm

4223507/A 01/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

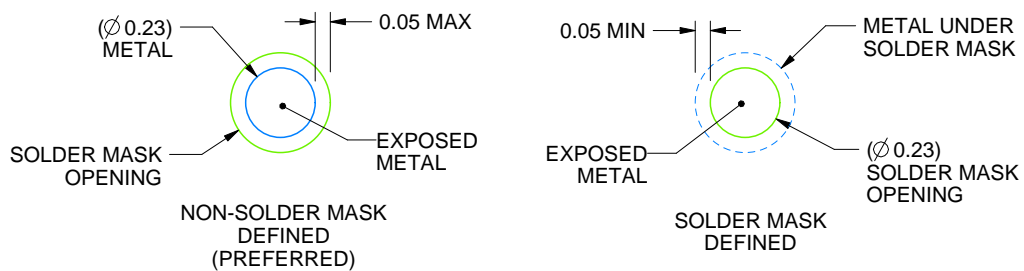
YFP0004

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:50X



SOLDER MASK DETAILS  
NOT TO SCALE

4223507/A 01/2017

NOTES: (continued)

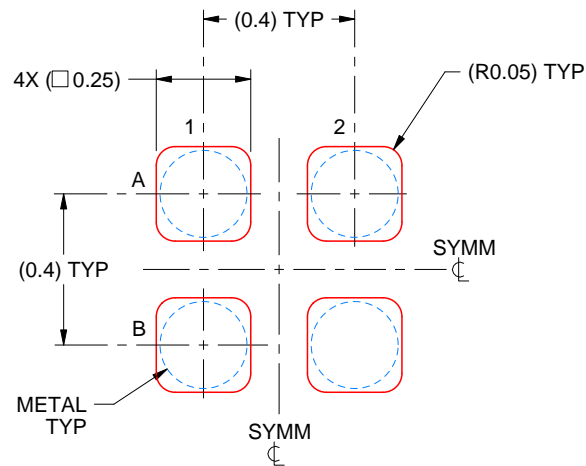
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

# EXAMPLE STENCIL DESIGN

YFP0004

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:50X

4223507/A 01/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



## 重要声明和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2024，德州仪器 (TI) 公司